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| APPLICATION NO. | FILING DATE | FIRST NAMED INVENTOR | ATTORNEY DOCKET NO. | CONFIRMATION NO. | | | |
|---|----------------|----------------------|---------------------|------------------|--|--|--|
| 10/044,686 | 01/11/2002 | Shiro Sakai | 08228/019001 | 9706 | | | |
| 22511 7: | 590 01/20/2006 | | EXAM | EXAMINER | | | |
| OSHA LIANG L.L.P. 1221 MCKINNEY STREET | | | SONG, MATTHEW J | | | | |
| SUITE 2800 | El Silesi | | ART UNIT | PAPER NUMBER | | | |
| HOUSTON, TX 77010 | | · | 1722 | | | | |

DATE MAILED: 01/20/2006

Please find below and/or attached an Office communication concerning this application or proceeding.

| | | Application No | - | Applicant(s) | | | |
|---|---|---|---|---|-------------|--|--|
| | | 10/044,686 | | SAKAI ET AL. | | | |
| Office Action Summary | | Examiner | | Art Unit | | | |
| | • | Matthew J. Song | | 1722 | | | |
| The MAILING DATE of this co Period for Reply | ommunication appea | ars on the cove | r sheet with the c | orrespondence add | tress – | | |
| A SHORTENED STATUTORY PER WHICHEVER IS LONGER, FROM - Extensions of time may be available under the p after SIX (6) MONTHS from the mailing date of i - If NO period for reply is specified above, the ma - Failure to reply within the set or extended period Any reply received by the Office later than three earned patent term adjustment. See 37 CFR 1. | THE MAILING DAT provisions of 37 CFR 1.136(this communication. ximum statutory period will d for reply will, by statute, ca months after the mailing di | (a). In no event, how apply and will expire ause the application to | OMMUNICATION ever, may a reply be times SIX (6) MONTHS from the become ABANDONE | N. nety filed the mailing date of this co D (35 U.S.C. § 133). | | | |
| Status | | | | | | | |
| 1)⊠ Responsive to communication | n(s) filed on <u>03 Nov</u> | vember 2005. | | | | | |
| 2a)⊠ This action is FINAL. | 2b)☐ This a | ction is non-fin | al. | | | | |
| 3) Since this application is in cor | 3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is | | | | | | |
| closed in accordance with the | practice under Ex | parte Quayle, | 1935 C.D. 11, 45 | 3 O.G. 213. | | | |
| Disposition of Claims | | | | | | | |
| 4)⊠ Claim(s) <u>1-16</u> is/are pending i | in the application. | | | | | | |
| 4a) Of the above claim(s) <u>7-11</u> | , - | rom considerat | tion. | | | | |
| 5) Claim(s) is/are allowed | | | | | | | |
| 6)⊠ Claim(s) <u>1-6 and 12-16</u> is/are | rejected. | | | | | | |
| 7)☐ Claim(s) is/are objecte | d to. | | | | | | |
| 8) Claim(s) are subject to | restriction and/or | election require | ment. | | | | |
| Application Papers | | | | | | | |
| 9)☐ The specification is objected to | by the Examiner. | | | | | | |
| 10)☐ The drawing(s) filed on | is/are: a) ☐ accep | oted or b) 🗌 ob | jected to by the E | Examiner. | | | |
| Applicant may not request that a | ny objection to the dr | awing(s) be held | in abeyance. See | 37 CFR 1.85(a). | | | |
| Replacement drawing sheet(s) ir | = | • | | | • • | | |
| 11)☐ The oath or declaration is obje | ected to by the Exa | miner. Note the | e attached Office | Action or form PT | O-152. | | |
| Priority under 35 U.S.C. § 119 | | | | | | | |
| 12)☐ Acknowledgment is made of a | claim for foreign p | riority under 35 | 5 U.S.C. § 119(a) | -(d) or (f). | | | |
| a) ☐ All b) ☐ Some * c) ☐ Non | e of: | | | | | | |
| 1.☐ Certified copies of the p | | | | | | | |
| 2. Certified copies of the p | | | | | | | |
| 3. Copies of the certified of | | | | d in this National S | Stage | | |
| application from the Inte | | • | * ** | | | | |
| * See the attached detailed Offic | e action for a list of | tne centilea c | opies not receive | а. | | | |
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| | | | | | | | |
| Attachment(s) | | | | | | | |
| Notice of References Cited (PTO-892) Notice of Draftsperson's Patent Drawing References. | eview (PTO-049) | 4) 🗌 | Interview Summary Paper No(s)/Mail Da | | | | |
| 3) X Information Disclosure Statement(s) (PTO- | | 5) 🔲 | | atent Application (PTO | -152) | | |
| Paper No(s)/Mail Date <u>11/3/05</u> . | | 6) 🔲 | Other: | | | | |
| U.S. Patent and Trademark Office PTOL-326 (Rev. 7-05) | Office Action | on Summary | | Part of Paper No./Mail I | Date 060115 | | |

DETAILED ACTION

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.

This application currently names joint inventors. In considering patentability of the claims under 35 U.S.C. 103(a), the examiner presumes that the subject matter of the various claims was commonly owned at the time any inventions covered therein were made absent any evidence to the contrary. Applicant is advised of the obligation under 37 CFR 1.56 to point out the inventor and invention dates of each claim that was not commonly owned at the time a later invention was made in order for the examiner to consider the applicability of 35 U.S.C. 103(c) and potential 35 U.S.C. 102(e), (f) or (g) prior art under 35 U.S.C. 103(a).

2. Claims 1-6 and 12-16 are rejected under 35 U.S.C. 103(a) as being unpatentable over Motoki et al (EP 0961328 A2) or Shakuda et al (JP 10-275933), where an English Abstract and computer translation (CT) have been provided, in view of Applicant's Admitted Prior Art (AAPA), and further in view of Borkowicz et al (US 5,422,779).

In a method of manufacturing a nitride semiconductor chip, note entire reference, Motoki et al teaches a GaN/GaN LED has a shape of an equilateral rhombus (Abstract) and scribing by cutting lines 24, 24, and cutting lines 25, 25..... which are at an angle of 120° with the cutting lines 25 ([0052] and Fig 18, this reads on applicant's cutting the substrate along two

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directions that form a 120° angle. Motoki et al also teaches forming GaN, which has hexagonal symmetry, and grown as a regular hexagon on a substrate ([0019]-[0020]), this reads on applicant's growing nitride crystals of a hexagonal system on a surface of a substrate.

In a method of forming a light emitting element, Shakuda et al teaches a semiconductor lamination part 10 of GaN, a first p-type electrode 8, and a second n-type electrode 9, where the electrodes are formed in opposite corners of a rhombus shaped chip (Abstract and Fig 1b).

Shakuda et al teaches the electrodes are placed on corners of the chip, as applicants, note Fig 3A and 3B; therefore reads on applicant's forming electrodes at opposing ends of a planar surface. Shakuda et al also teaches a line is put in with a diamond pen and the chip is obtained by dividing and the acute angle of the rhombus is 60° (CT [0014]). Shakuda et al teaches an acute angle of 60°; therefore by simply geometry, the obtuse angle must be 120° since the opposite angles are the same and the sides of the rhombus are all equal. Therefore, Shakuda et al inherently teaches cutting the substrate along two direction that form an angle of 120°. Also, note Mushika et al (US 2005/0168798), which teaches 60° angles at acute vertexes and 120° for obtuse vertexes for a rhombus ([0156]), which supports the Examiner's position of inherency. Shakuda et al also teaches a sapphire substrate ([0013]) and the rhombus configuration allows cutting without cracking, when carrying out separation from a wafer at each chip ([0021]).

Motoki et al and Shakuda et al do not teach grinding a back surface of the substrate.

In a method of forming GaN LEDs, AAPA teaches GaN crystals having a hexagonal system are grown on a sapphire substrate and after the crystals are grown the substrate is cut into chips for use as devices such as light emitting diodes. AAPA also teaches the back surface of the substrate is first ground and then scratches are made on the front or back side of the substrate

using a diamond pen or the like. After the substrate is ground to the desired thickness, the substrate is cut along the direction of the scratches. The process of grinding the substrate is performed so that the substrate will easily split (page 1-2 of the specification).

It would have been obvious to a person of ordinary skill in the art at the time of the invention to modify Motoki et al or Shakuda et al by grinding the back of the substrate and scratching to easily split the substrate, as taught by AAPA.

The combination of Motoki et al and AAPA or the combination of Shakuda et al and AAPA does not teach triangular electrodes.

In a method of making a semiconductor chip, note entire reference, Borkowicz et al teaches electrodes can be of other shapes, such as square, hexagonal, triangular or oval (col 6, ln 1-10). It would have been obvious to a person of ordinary skill in the art at the time of the invention to modify the combination of Motoki et al and AAPA or the combination of Shakuda et al and AAPA by changing the shape of the electrode to be triangular, as taught by Borkowicz et al because changes in shape are held to be obvious (MPEP 2144.04 IV. B).

Referring to claim 1, the combination of Motoki et al, AAPA and Borkowicz et al teaches a p-electrode at a top portion of a LED, an n-electrode on the opposite side, on a bottom portion of an LED and a light emitting section in the middle 19, this reads on applicant's forming a light emitting section on a central section of the nitride semiconductor chip and forming an electrode at opposing ends of a planar surface of the nitride semiconductor because the thickness of the chip would read on the planar surface and the electrodes are on opposite side of that plane.

Referring to claims 2, 3 and 13, the combination of Motoki et al, AAPA and Borkowicz et al teaches scratching the front or back of the substrate (AAPA, Page 1 of the instant specification).

Referring to claims 4 and 14, the combination of Motoki et al, AAPA and Borkowicz et al teaches an equilateral rhombus ('328 Abstract, col 9, ln 5-15 and claim 4).

Referring to claims 5 and 15, the combination of Motoki et al, AAPA and Borkowicz et al teaches sapphire (AAPA page 1 and '328 [0005]).

Referring to claims 6 and 16, the combination of Motoki et al, AAPA and Borkowicz et al teaches GaN ('328 Abstract).

Response to Arguments

- 3. Applicant's arguments with respect to claims 1-6 and 12-16 have been considered but are moot in view of the new ground(s) of rejection.
- 4. Applicant's arguments filed 11/3/2005 have been fully considered but they are not persuasive.

Applicant's argument that Motoki teaches difficulty in cutting sapphire is noted but is not found persuasive. Applicants argue that Motoki et al teaches away from the claimed invention because applicant's invention is capable of being used on sapphire. Firstly, independent claim 1 does not require using sapphire; therefore this argument is not applicable since sapphire is not required. Secondly, regarding dependent claim 5, Motoki teaches there are difficultly cutting sapphire, however sapphire is known to be a substrate which has been cut previously; therefore Motoki merely teaches a preferred embodiment, which does not use sapphire as a substrate. A

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reference may be relied upon for all that it would have reasonably suggested to one having ordinary skill in the art, including non-preferred embodiments (MPEP 2123).

Conclusion

5. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure.

Naruse et al (US 5,838,070) teaches pad electrodes formed in a triangular shape (col 10, ln 15-30).

Kuroiwa et al (US 6,187,622) teaches an upper electrodes has a triangular shape (col 3, ln 45-55).

6. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

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7. Any inquiry concerning this communication or earlier communications from the examiner

should be directed to Matthew J. Song whose telephone number is 571-272-1468. The examiner

can normally be reached on M-F 9:00-5:00.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, Duane Smith can be reached on 571-272-1166. The fax phone number for the

organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent

Application Information Retrieval (PAIR) system. Status information for published applications

may be obtained from either Private PAIR or Public PAIR. Status information for unpublished

applications is available through Private PAIR only. For more information about the PAIR

system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR

system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Matthew J Song

Examiner

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MJS January 15, 2006

> ROBERT KUNEMUND PRIMARY EXAMINER